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CONTENTS

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BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Diamondlike photonic band-gap crystal with a sizable band gap	3517
K. M. Leung	
Temperature dependence of non-Debye disorder in doped manganites	3520
C. Meneghini, R. Cimino, S. Pascarelli, S. Mobilio, C. Raghu, and D. D. Sarma	
Order- N method to calculate the local density of states	3524
Ju Li and Sidney Yip	
Violation of particle number conservation in the GW approximation	3528
Arno Schindlmayr	
Structural and electronic properties of alkaline-earth fluorohalides under pressure	3532
G. Kalpana, B. Palanivel, I. B. Shameem Banu, and M. Rajagopalan	
Electronic structure of indium oxide using cluster calculations	3536
Isao Tanaka, Masataka Mizuno, and Hirohiko Adachi	
Normal Fermi-liquid behavior of quasiholes in the spin-polaron model for copper oxides	3540
G. Jackeli and V. Yu. Yushankhai	
Effective one-band electron-phonon Hamiltonian for nickel perovskites	3544
J. Loos and H. Fehske	
Spin-charge separation in angle-resolved photoemission spectra	3548
Hidekatsu Suzuura and Naoto Nagaosa	
Interrelation between persistent photoconductivity and oxygen order in $\text{GdBa}_2\text{Cu}_3\text{O}_x$ thin films	3552
J. Guimpel, B. Maiorov, E. Osquiguil, G. Nieva, and F. Pardo	

Semiconductors I: bulk

Theoretical studies of native defects in cubic boron nitride	3556
P. Piquini, R. Mota, T. M. Schmidt, and A. Fazzio	
Lattice dynamics of GaN: Effects of $3d$ electrons	3560
K. Karch, F. Bechstedt, and T. Pletl	
Electronic structure of GaN stacking faults	3564
Z. Z. Bandić, T. C. McGill, and Z. Ikonić	
Charge transfer between In and Ga in InGaAs-based alloys	3567
R. Manor, O. Brafman, and R. F. Kopf	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Quantitative theory of diffraction by carbon nanotubes	3571
Ph. Lambin and A. A. Lucas	
Segregation of boron on the cluster-modeled $\text{Si}(111)\sqrt{3}\times\sqrt{3}R30^\circ$ -B hydrogenated surface	3575
Sanwu Wang, M. W. Radny, and P. V. Smith	
Atomic and electronic structures of rebonded B -type steps on the $\text{Si}(001)$ - 2×1 surface	3579
Takuji Komura, Takafumi Yao, and Masamichi Yoshimura	
Island-size dependence of reconstructed structures on $\text{Si}(111)$	3583
Makoto Itoh	

(Continued)

Strong optical anisotropy of the single-domain 5×2 -Au reconstruction on vicinal Si(111)	3587
J. R. Power, P. Weightman, and J. D. O'Mahony	
Influence of microwave fields on the electron tunneling through a quantum dot	3591
Qing-feng Sun and Tsung-han Lin	
Physics of optimal resonant tunneling	3595
Paul N. Racec, Toma Stoica, Corneliu Popescu, Mihail Lepsa, and Th. G. van de Roer	
Composite fermions in periodic and random antidot lattices	3598
J. H. Smet, D. Weiss, K. von Klitzing, P. T. Coleridge, Z. W. Wasilewski, R. Bergmann, H. Schweizer, and A. Scherer	
Effect of Landau-level mixing for electrons in a random magnetic field	3602
Ming-Che Chang, Min-Fong Yang, and Tzay-Ming Hong	
Quantum Hall spherical systems: The filling fraction	3606
P. Sitko, J. J. Quinn, and D. C. Marinescu	
Charging dynamics of InAs self-assembled quantum dots	3609
G. Medeiros-Ribeiro, J. M. Garcia, and P. M. Petroff	
Dephasing-induced vacuum-field Rabi splittings in microcavities with quantum wells	3613
Girish S. Agarwal and S. Dutta Gupta	
Isotropic and anisotropic contributions to the optical reflection of Si(001)- 2×1	3617
H. Wormeester, D. J. Wentink, and A. van Silfhout	
Optical properties of InSb layers confined by InP	3621
T. Utzmeier, G. Armelles, P. A. Postigo, and F. Briones	
Surface physics, low-dimensional systems, and related topics	
Tight-binding molecular-dynamics simulations of C_{61} formation and decomposition in $C+C_{60}$ collisions	3624
Yunlong Cui and Lei Liu	
Quasiparticle energies in clusters determined via total-energy differences: Application to C_{60} and Na_4	3628
Giancarlo Cappellini, Francesco Casula, Jinlong Yang, and Friedhelm Bechstedt	
Influence of surface structural disorder on linewidths in angle-resolved photoemission spectra	3632
F. Theilmann, R. Matzdorf, G. Meister, and A. Goldmann	
Atomic and local electronic structure of Gd thin films studied by STM and STS	3636
R. Pascal, Ch. Zarnitz, M. Bode, and R. Wiesendanger	
Influence of dislocations in Thomson's problem	3640
A. Pérez-Garrido, M. J. W. Dodgson, and M. A. Moore	
Energy loss in electronic emission from solid surfaces	3644
J. Osma, P. M. Echenique, and N. Mårtensson	
Microscopic carbon distribution in $Si_{1-y}C_y$ alloys: A Raman scattering study	3648
M. Meléndez-Lira, J. D. Lorentzen, J. Menéndez, W. Windl, N. G. Cave, R. Liu, J. W. Christiansen, N. D. Theodore, and J. J. Candelaria	
Electrochemical deposition of copper onto Pt(111) in the presence of (bi)sulfate anions	3651
C. A. Lucas, N. M. Marković, and P. N. Ross	
Analytical asymptotic structure of the Kohn-Sham exchange potential at a metal surface	3655
Alexander Solomatin and Virahat Sahni	

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Metallic conductivity at low temperatures in poly(3,4-ethylenedioxythiophene) doped with PF ₆	3659
A. Aleshin, R. Kiebooms, Reghu Menon, F. Wudl, and A. J. Heeger	
Exchange-correlation energy of a hole gas including valence band coupling	3664
P. A. Bobbert, H. Wieldraaijer, R. van der Weide, M. Kemerink, P. M. Koenraad, and J. H. Wolter	
Electronic calculations on the MgTiOBO ₃ warwickite: A real-space renormalization approach	3672
D. C. Marcucci, A. Latgé, E. V. Anda, M. Matos, and J. C. Fernandes	
Structural and electronic properties of the martensitic alloys TiNi, TiPd, and TiPt	3678
Y. Y. Ye, C. T. Chan, and K. M. Ho	
Valence states of Yb in Yb ₅ Si ₃	3690
M. Rams, K. Królas, P. Bonville, E. Alleno, C. Godart, D. Kaczorowski, and F. Canepa	
Excitons in quasi-one-dimensional organics: Strong correlation approximation	3697
Z. G. Yu, A. Saxena, and A. R. Bishop	
Complete pseudohole and heavy-pseudoparticle operator representation for the Hubbard chain	3717
J. M. P. Carmelo and N. M. R. Peres	
Coherent propagation of interacting particles in a random potential: The mechanism of enhancement	3742
I. V. Ponomarev and P. G. Silvestrov	
Spin fluctuation and the transport mechanism in vanadium oxide spinels with a metal-insulator transition	3760
Masashige Onoda, Hiroyoshi Imai, Yasushi Amako, and Hiroshi Nagasawa	
Charge-injection instability in perfect insulators	3772
Thomas Christen	
Path-integral theory for light-absorption spectra of many-electron systems in insulating states due to strong long-range Coulomb repulsion: Nonlinear coupling between charge and spin excitations	3779
Norikazu Tomita and Keiichiro Nasu	
Hofstadter butterfly for the hexagonal lattice	3787
Godfrey Gumbs and Paula Fekete	
Effects of the quantum fluctuations on the nonlinear optical response of trans-polyacetylene to the static external electric field	3792
Akira Takahashi	
Lattice-gas model to understand voltage profiles of LiNi _x Mn _{2-x} O ₄ /Li electrochemical cells	3800
Tao Zheng and J. R. Dahn	

Semiconductors I: bulk

Structural, dynamical, electronic, and bonding properties of laser-heated silicon: An <i>ab initio</i> molecular-dynamics study	3806
Pier Luigi Silvestrelli, Ali Alavi, Michele Parrinello, and Daan Frenkel	
Unstable displacement defects and hydrogen trapping in GaAs	3813
H. J. Stein and J. C. Barbour	
Interstitial oxygen in germanium and silicon	3820
Emilio Artacho, Félix Ynduráin, Bernard Pajot, Rafael Ramírez, Carlos P. Herrero, Ludmila I. Khirunencko, Kohei M. Itoh, and Eugene E. Haller	
Formation and relaxation of exciton-carbon acceptor complexes in GaAs	3834
M. Grassi Alessi, A. Patané, A. Polimeni, M. Capizzi, F. Martelli, P. Borri, M. Gurioli, and M. Colocci	
Polarization dependence of the ultrafast photoluminescence of oriented poly(<i>p</i> -phenylenevinylene)	3838
G. R. Hayes, I. D. W. Samuel, and R. T. Phillips	
Extrinsic and intrinsic dc photoconductivity in a conjugated polymer	3844
S. Barth, H. Bässler, H. Rost, and H. H. Hörhold	

(Continued)

Evidence for triplet interchain polaron pairs and their transformations in polyphenylenevinylene	3852
V. Dyakonov, G. Rösler, M. Schwoerer, and E. L. Frankevich	
Role of the electron temperature distribution on magnetoresistance in bulk semiconductors	3863
G. González de la Cruz, Yu. G. Gurevich, and V. V. Prosentsov	
Determination of deformation-potential constants of Cu ₂ O by microwave cyclotron resonance	3871
T. Ohyama, T. Ogawa, and H. Nakata	
Nonlinear optical effects in porous silicon: Photoluminescence saturation and optically induced polarization anisotropy	3875
Al. L. Efros, M. Rosen, B. Averboukh, D. Kovalev, M. Ben-Chorin, and F. Koch	
Group-IV semiconductor compounds	3885
M. A. Berding, A. Sher, and M. van Schilfgaarde	
Semiconductors II: surfaces, interfaces, microstructures, and related topics	
One-dimensional character of miniband transport in doped GaAs/AlAs superlattices	3892
Yu. A. Pusep, A. J. Chiquito, S. Mergulhão, and J. C. Galzerani	
Kinetic processes in the transition from Ag(111) crystallites to ($\sqrt{3} \times \sqrt{3}$)R30° domains for Ag/Si(111)-(7×7)	3897
J.-K. Zuo and J. F. Wendelken	
Theory of reflectance anisotropy of clean and hydrogenated (001) diamond surfaces	3903
V. I. Gavrilenko and F. Bechstedt	
Optical investigation of CdTe monomolecular islands in wide ZnTe/(Zn,Mg)Te quantum wells: Evidence of a vertical self-ordering	3907
Pierre Lefebvre, Vincent Calvo, Noël Magnea, Thierry Taliercio, Jacques Allègre, and Henry Mathieu	
Bifurcations and the transition to chaos in the resonant-tunneling diode	3913
T. S. Monteiro, D. Delande, A. J. Fisher, and G. S. Boebinger	
Crossover from strong to weak confinement for excitons in shallow or narrow quantum wells	3922
Rita Claudia Iotti and Lucio Claudio Andreani	
Generalized $\mathbf{k} \cdot \mathbf{p}$ perturbation theory for atomic-scale superlattices	3933
H. Yi and M. Razeghi	
Fermi-edge singularities in photoluminescence from modulation-doped GaAs quantum wells	3937
S. A. Brown, Jeff F. Young, Z. Wasilewski, and P. T. Coleridge	
Coherent transient in photoluminescence of excitonic molecules in GaAs quantum wells	3941
A. L. Ivanov, Hailin Wang, Jagdeep Shah, T. C. Damen, L. V. Keldysh, H. Haug, and L. N. Pfeiffer	
Level broadening effects in quantum kinetic equations: Hot luminescence from a quantum wire near the optical-phonon-emission threshold	3952
Michal Rokni and Y. Levinson	
Repulsion of energies of delocalized states in a double-layer system in a strong magnetic field	3965
A. Gramada and M. E. Raikh	
Electron pump in multiple-tunnel junctions	3972
K. Tsukagoshi, K. Nakazato, H. Ahmed, and K. Gamo	
Photon assisted transport in superlattices beyond the nearest-neighbor approximation	3976
Xian-Geng Zhao, G. A. Georgakis, and Qian Niu	
Mesoscopic conductance and its fluctuations at a nonzero Hall angle	3982
Shanhui Xiong, N. Read, and A. Douglas Stone	
Coulomb drag in compressible quantum Hall states	4013
Ido Ussishkin and Ady Stern	
Electron-flow diffraction in a point contact	4023
Yu. F. Komnik, V. V. Andrievskii, and S. V. Rozhok	
Acoustoelectric effects in quantum constrictions	4028
Frank A. Maaß and Y. Galperin	

Spectral ellipsometry investigation of $\text{Zn}_{0.53}\text{Cd}_{0.47}\text{Se}$ lattice matched to InP	4037
Todd Holden, Prakhya Ram, Fred H. Pollak, J. L. Freeouf, B. X. Yang, and M. C. Tamargo	
Absorption spectra and optical transitions in InAs/GaAs self-assembled quantum dots	4047
M. A. Cusack, P. R. Briddon, and M. Jaros	
Persistent spectral-hole-burning spectroscopy of CuCl quantum cubes	4051
Naru Sakakura and Yasuaki Masumoto	
Determination of second-order nonlinear coefficients in semiconductors using pseudospin equations for three-level systems	4056
D. C. Hutchings and J. M. Arnold	
Magnetopolaritons in a semiconductor quantum well microcavity	4068
J. Tignon, R. Ferreira, J. Wainstain, C. Delalande, P. Voisin, M. Voos, R. Houdré, U. Oesterle, and R. P. Stanley	
Strong optical nonlinearities in gallium and indium selenides related to inter-valence-band transitions induced by light pulses	4075
A. Segura, J. Bouvier, M. V. Andrés, F. J. Manjón, and V. Muñoz	
Kardar-Parisi-Zhang growth of amorphous silicon on Si/SiO ₂	4085
M. Lütt, J. P. Schlomka, M. Tolan, J. Stettner, O. H. Seeck, and W. Press	
Phase transitions on Si(113): A high-temperature scanning-tunneling-microscopy study	4092
H. Hibino and T. Ogino	
Coulomb drag in double-layer electron systems at even-denominator filling factors	4098
S. Sakhi	
Effective-mass reproducibility of the nearest-neighbor sp^3s^* models: Analytic results	4102
Timothy B. Boykin, Gerhard Klimeck, R. Chris Bowen, and Roger Lake	
Excitons in T-shaped quantum wires	4108
S. Glutsch, F. Bechstedt, W. Wegscheider, and G. Schedelbeck	
Continuum treatment of phonon polaritons in semiconductor heterogeneous structures	4115
F. Comas, C. Trallero-Giner, and M. Cardona	
Collective excitation in GaAs-Al _x Ga _{1-x} As quantum wires: Multisubband model	4128
Paulo César Miranda Machado, José Roberto Leite, Francisco Aparecido Pinto Osório, and Antônio Newton Borges	
Theory of electron transport through a periodic array of devices with transverse exit leads	4132
John L. Bohn	
Surface physics, low-dimensional systems, and related topics	
Reflection high-energy electron-diffraction study of melting and solidification of Pb on graphite	4141
Z. H. Zhang, P. Kulatunga, and H. E. Elsayed-Ali	
Optimized epitaxial growth of Fe on Ag(001)	4149
D. E. Bürgler, C. M. Schmidt, D. M. Schaller, F. Meisinger, R. Hofer, and H.-J. Güntherodt	
Geometry effects on the van der Waals force in atomic force microscopy	4159
Peter Johansson and Peter Apell	
Sequential <i>in situ</i> STM imaging of electrodisolving copper single-crystal domains in aqueous perchloric acid: Kinetics and mechanism of the interface evolution	4166
S. G. Aziz, M. E. Vela, G. Andreasen, R. C. Salvarezza, A. Hernández-Creus, and A. J. Arvia	
Spectral dependence of femtosecond relaxation and coherent phonon excitation in C ₆₀ films	4176
V. M. Farztdinov, A. L. Dobryakov, V. S. Letokhov, Yu. E. Lozovik, Yu. A. Matveets, S. A. Kovalenko, and N. P. Ernsting	
Topographic and crystallographic characterization of a grazing-ion-bombarded GaAs(110) surface by time-of-flight ion-scattering spectrometry	4186
J. E. Gayone, R. G. Pregliasco, G. R. Gómez, E. A. Sánchez, and O. Grizzi	
Atomic-structure characterization of a H:GaAs(110) surface by time-of-flight ion-scattering spectrometry	4194
J. E. Gayone, R. G. Pregliasco, E. A. Sánchez, and O. Grizzi	

<i>Ab initio</i> calculations of the atomic and electronic structure of clean and hydrogenated diamond (110) surfaces	4203
G. Kern and J. Hafner	
Discrete-row growth of xenon adsorbed on the vicinal Pt(997) surface: Comparison between theory and experiment	4211
V. Pouthier, C. Ramseyer, C. Girardet, K. Kuhnke, V. Marsico, M. Blanc, R. Schuster, and K. Kern	
Sampling-induced hidden cycles in correlated random rough surfaces	4224
H.-N. Yang, Y.-P. Zhao, A. Chan, T.-M. Lu, and G.-C. Wang	
Initial growth morphology in a heteroepitaxial system at low temperature: Fe on Ag(100)	4233
M. Canepa, S. Terreni, P. Cantini, Andrea Campora, and L. Mattera	
Surface roughening during plasma-enhanced chemical-vapor deposition of hydrogenated amorphous silicon on crystal silicon substrates	4243
D. M. Tanenbaum, A. L. Laracuente, and Alan Gallagher	
Energy- and angle-dependent excitation probability of sputtered metastable silver atoms	4251
W. Berthold and A. Wucher	
Static and dynamic properties of frictional phenomena in a one-dimensional system with randomness	4261
Takaaki Kawaguchi and Hiroshi Matsukawa	
SiC formation by reaction of Si(001) with acetylene: Electronic structure and growth mode	4266
G. Dufour, F. Rochet, F. C. Stedile, Ch. Poncey, M. De Crescenzi, R. Gunnella, and M. Froment	

COMMENTS

Comment on “Step dynamics and equilibrium structure of monoatomic steps on Si(100)-2×1”	4283
H. J. W. Zandvliet, W. Wulfhekel, B. Hendriksen, and Bene Poelsema	

Errata

Erratum: Theory of arbitrarily polarized quantum Hall states: Filling fractions and wave functions [Phys. Rev. B 54 , 8688 (1996)]	4284
Sudhansu S. Mandal and V. Ravishankar	
Erratum: Bose-Einstein statistics of orthoexcitons generated by two-photon resonant absorption in cuprous oxide [Phys. Rev. B 55 , 7609 (1997)]	4284
T. Goto, M. Y. Shen, S. Koyama, and T. Yokouchi	

Cumulative Author Index	4285
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